# MAX515E 10-BIT DIGITAL-TO-ANALOG CONVERTERS

Features

- 10-Bit CMOS Voltage Output DAC in an 8-Terminal Package

- 5V Single Supply Operation

- 3-Wire Serial Interface

- High-Impedance Reference Inputs

- Voltage Output Range:2 Times the Reference Input Voltage

- Internal Power-On Reset

- Low Power Consumption:1.75mW(Max）

- Update Rate of 1.21 MHz

- Settling Time to 0.5 LSB:12.5 μs(Typ)

- Monotonic Over Temperature

- Pin Compatible With the TLC5615

DIP-8

SOP-8

MSOP-8
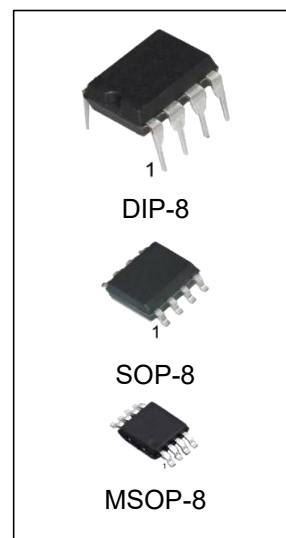
Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
MAX515EIN	DIP-8	X515EI	TUBE	2000pcs/box
MAX515ECN	DIP-8	X515EC	TUBE	2000pcs/box
MAX515EIM/TR	SOP-8	X515EI	REEL	2500pcs/reel
MAX515ECM/TR	SOP-8	X515EC	REEL	2500pcs/reel
MAX515EIMM/TR	MSOP-8	X515EI	REEL	3000pcs/reel
MAX515ECMM/TR	MSOP-8	X515EC	REEL	3000pcs/reel

Description

The MAX515E is a 10-bit voltage output digital-to-analog converter (DAC) with a buffered reference input (high impedance). The DAC has an output voltage range that is two times the reference voltage, and the DAC is monotonic. The device is simple to use, running from a single supply of 5 V. A power-on-reset function is incorporated to ensure repeatable start-up conditions.

Digital control of the MAX515E is over a three-wire serial bus that is CMOS compatible and easily interfaced to industry standard microprocessor and micro controller devices. The device receives a 16-bit data word to produce the analog output. The digital inputs feature Schmitt triggers for high noise immunity. Digital communication protocols include the SPI™, QSPI™, and Microwire™ standards.

The 8-terminal small-outline D package allows digital control of analog functions in space-critical applications. The MAX515EC is characterized for operation from 0℃ to 70℃. The MAX515EI is characterized for operation from -40℃ to 85℃.
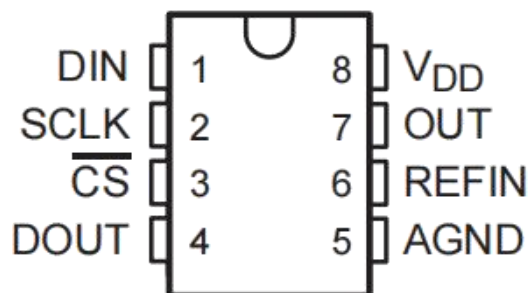
Applications

- Battery-Powered Test Instruments
- Digital Offset and Gain Adjustment
- Battery Operated/Remote Industrial Controls
- Machine and Motion Control Devices
- Cellular Telephones

Functional block diagram
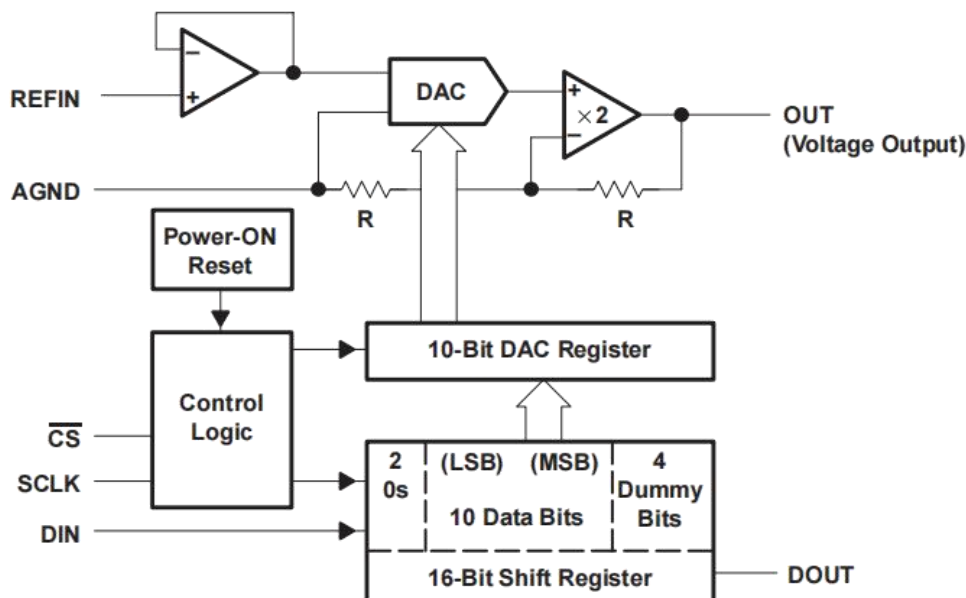
Pin Configuration

DIP-8/SOP-8/MSOP-8

Terminal Functions

| TERMINAL | | I/O | DESCRIPTION |
NAME	NO.		
DIN	1	I	Serial data input
SCLK	2	I	Serial clock input
CS	3	I	Chip select, active low
DOUT	4	O	Serial data output for daisy chaining
AGND	5		Analog ground
REFIN	6	I	Reference input
OUT	7	O	DAC analog voltage output
V_{DD}	8		Positive power supply

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

Condition		Min	Max
Supply voltage (VDD to AGND)		-	7 V
Digital input voltage range to AGND		− 0.3 V	VDD + 0.3 V
Reference input voltage range to AGND		− 0.3 V	VDD + 0.3 V
Output voltage at OUT from extrnal source		-	VDD + 0.3 V
Continuous current at any terminal		-20mA	+20mA
Operating free-air temperature range,T_A:	MAX515EC	0℃	70℃
	MAX515EI	-40℃	85℃
Storage temperature range, T_{stg}		-65℃	150℃
Lead Temperature (Soldering, 10 seconds)		-	245℃

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability

Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{DD}		4.5	5	5.5	V
High-level digital input voltage, V_{IH}		2.4			V
Low-level digital input voltage, V_{IL}				0.8	V
Reference voltage, V_{ref} to REFIN terminal		2	2.048	$V_{DD}-2$	V
Load resistance, R_L		2			kΩ
Operating free-air temperature, T_A	MAX515EC	0		70	℃
	MAX515EI	−40		85	℃

Electrical Characteristics

over recommended operating free-air temperature range, VDD = 5 V ±5%, Vref = 2.048 V (unless otherwise noted) static DAC specifications

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			10			bits
Integral nonlinearity, end point adjusted (INL)		V_{ref} = 2.048 V,See Note 1			±1	LSB
Differential nonlinearity (DNL)		V_{ref} = 2.048 V,See Note 2		±0.1	±0.5	LSB
E_{ZS} Zero-scale error (offset error at zero scale)		V_{ref} = 2.048 V,See Note 3			±3	LSB
Zero-scale-error temperature coefficient		V_{ref} = 2.048 V,See Note 4		3		ppm/℃
E_G Gain error		V_{ref} = 2.048 V,See Note 5			±3	LSB
Gain-error temperature coefficient		V_{ref} = 2.048 V,See Note 6		1		ppm/℃
PSRR Power-supply rejection ratio	Zero scale	See Notes 7 and 8	80			dB
	Gain		80			
Analog full scale output		R_L = 100 kΩ		$2V_{ref}(1023/1024)$		V

1. The relative accuracy or integral nonlinearity (INL), sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors (see text).
2. The differential nonlinearity (DNL), sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.
3. Zero-scale error is the deviation from zero-voltage output when the digital input code is zero (see text).
4. Zero-scale-error temperature coefficient is given by:
   EZS TC = [EZS (Tmax) – EZS (Tmin)]/Vref $\times 10^6$/(Tmax – Tmin).
5. Gain error is the deviation from the ideal output (Vref – 1 LSB) with an output load of 10 kΩ excluding the effects of the zero-scale error.
6. Gain temperature coefficient is given by: EG TC = [EG(Tmax) – EG (Tmin)]/Vref $\times 10^6$/(Tmax – Tmin).
7. Zero-scale-error rejection ratio (EZS-RR) is measured by varying the VDD from 4.5 V to 5.5 V dc and measuring the proportion of this signal imposed on the zero-code output voltage.
8. Gain-error rejection ratio (EG-RR) is measured by varying the VDD from 4.5 V to 5.5 V dc and measuring the proportion of this signal imposed on the full-scale output voltage after subtracting the zero-scale change.

Voltage Output (Out)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_O	Voltage output range	R_L = 10 kΩ	0		V_{DD}–0.4	V
	Output load regulation accuracy	$V_{O(OUT)}$ = 2 V, R_L = 2 kΩ			0.5	LSB
I_{OSC}	Output short circuit current	OUT to V_{DD} or AGND		20		mA
$V_{OL(low)}$	Output voltage, low-level	$I_{O(OUT)}$ ≤ 5 mA			0.25	V
$V_{OH(high)}$	Output voltage, high-level	$I_{O(OUT)}$ ≤ –5 mA	4.75			V

Electrical Characteristics

over recommended operating free-air temperature range, V_{DD} = 5 V ± 5%, Vref = 2.048 V (unless otherwise noted) (continued) reference input (REFIN)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_I	Input voltage		0		V_{DD}–2	V
r_i	Input resistance			10		MΩ
C_i	Input capacitance			5		pF

digital inputs (DIN, SCLK, CS)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH}	High-level digital input voltage		2.4			V
V_{IL}	Low-level digital input voltage				0.8	V
I_{IH}	High-level digital input current	V_I = V_{DD}			±1	µA
I_{IL}	Low-level digital input current	V_I = 0			±1	µA
C_i	Input capacitance			8		pF

digital output (DOUT)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	Output voltage, high-level	I_O = –2 mA	V_{DD}–1			V
V_{OL}	Output voltage, low-level	I_O = 2 mA			0.4	V

power supply

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{DD} Supply voltage			4.5	5	5.5	V
I_{DD} Power supply current	V_{DD} = 5.5 V, No load, All inputs = 0 V or V_{DD}	V_{ref} = 0		150	250	µA
	V_{DD} = 5.5 V, No load, All inputs = 0 V or V_{DD}	V_{ref} = 2.048 V		230	350	µA

analog output dynamic performance

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Signal-to-noise + distortion, S/(N+D)	V_{ref} = 1 V_{pp} at 1 kHz + 2.048 Vdc, code = 11 1111 1111, See Note 9	60			dB

NOTE 9: The limiting frequency value at 1 Vpp is determined by the output-amplifier slew rate.

digital input timing requirements (see Figure 1)

	PARAMETER	MIN	TYP	MAX	UNIT
$t_{su(DS)}$	Setup time, DIN before SCLK high	45			ns
$t_{h(DH)}$	Hold time, DIN valid after SCLK high	0			ns
$t_{su(CSS)}$	Setup time, $\overline{CS}$ low to SCLK high	1			ns
$t_{su(CS1)}$	Setup time, $\overline{CS}$ high to SCLK high	50			ns
$t_{h(CSH0)}$	Hold time, SCLK low to $\overline{CS}$ low	1			ns
$t_{h(CSH1)}$	Hold time, SCLK low to $\overline{CS}$ high	0			ns
$t_{w(CS)}$	Pulse duration, minimum chip select pulse width high	20			ns
$t_{w(CL)}$	Pulse duration, SCLK low	25			ns
$t_{w(CH)}$	Pulse duration, SCLK high	25			ns

output switching characteristic

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{pd(DOUT)}$ Propagation delay time, DOUT	C_L = 50 pF			50	ns

Operating Characteristics

over recommended operating free-air temperature range, V_{DD} = 5 V ±5%, Vref = 2.048 V (unless otherwise noted) analog output dynamic performance

| PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR Output slew rate	C_L = 100 pF, T_A = 25℃	R_L = 10 kΩ	0.3	0.5		V/µs
t_S Output settling time	To 0.5 LSB, R_L = 10 kΩ,	C_L = 100 pF, See Note 10		12.5		µs
Glitch energy	DIN = All 0s to all 1s				5	Nv • s

NOTE 10: Settling time is the time for the output signal to remain within ±0.5 LSB of the final measured value for a digital input code change of 000 hex to 3FF hex or 3FF hex to 000 hex.

reference input (REFIN)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Reference feedthrough	REFIN = 1 V_{pp} at 1 kHz + 2.048 Vdc (see Note 11)			−80		dB
Reference input bandwidth (f–3dB)	REFIN = 0.2 V_{pp} + 2.048 Vdc	REFIN = 0.2 V_{pp} + 2.048 Vdc		30		kHz

NOTE 11: Reference feed through is measured at the DAC output with an input code = 000 hex and a Vref input = 2.048 Vdc + 1 Vpp at 1 kHz.
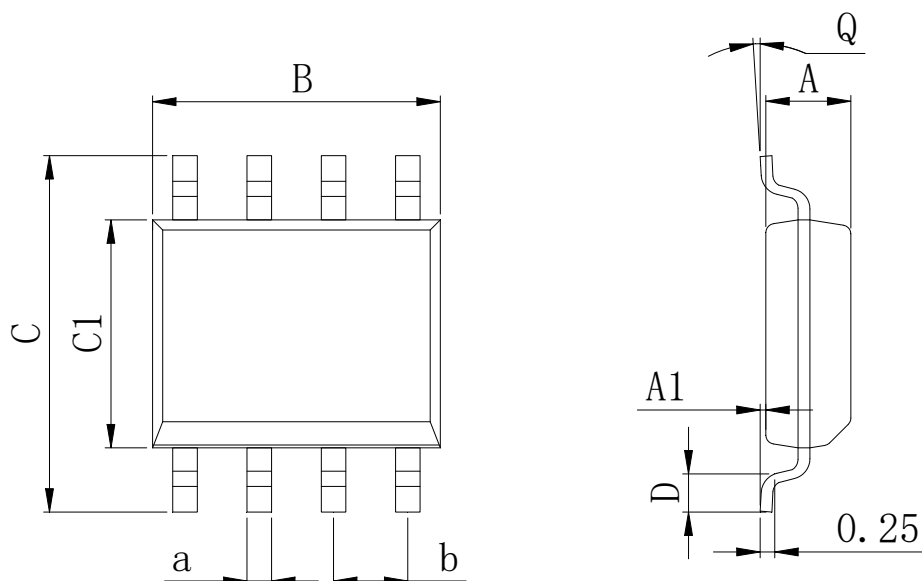
Parameter Measurement Information
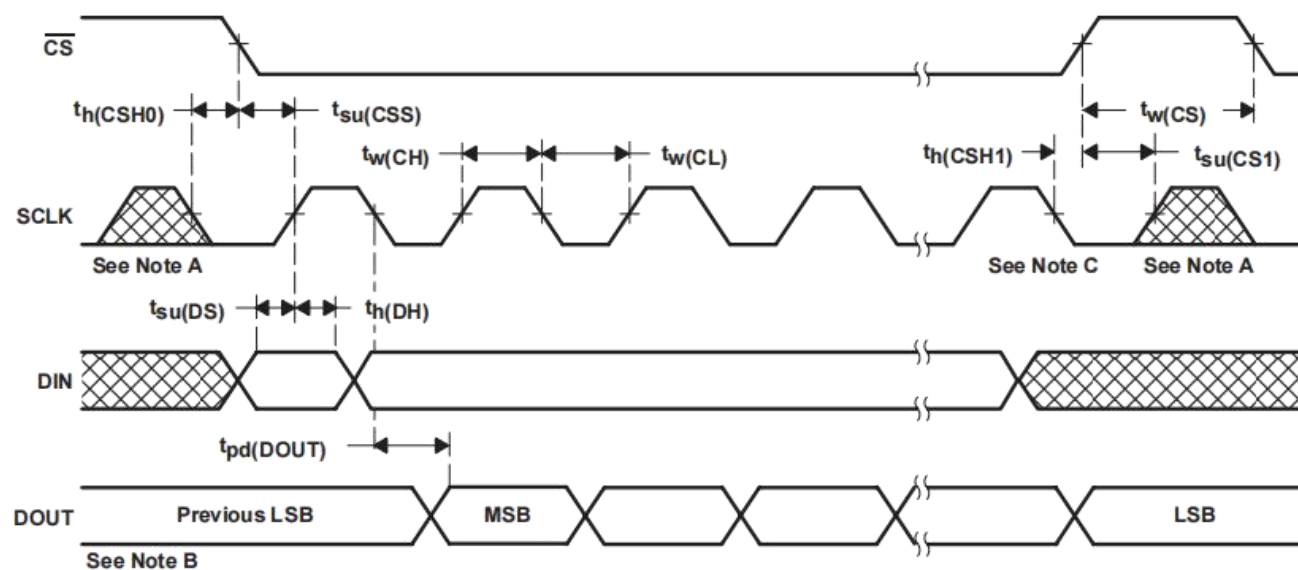
A. The input clock, applied at the SCLK terminal, should be inhibited low when CS is high to minimize clock feedthrough.
B. Data input from preceeding conversion cycle.
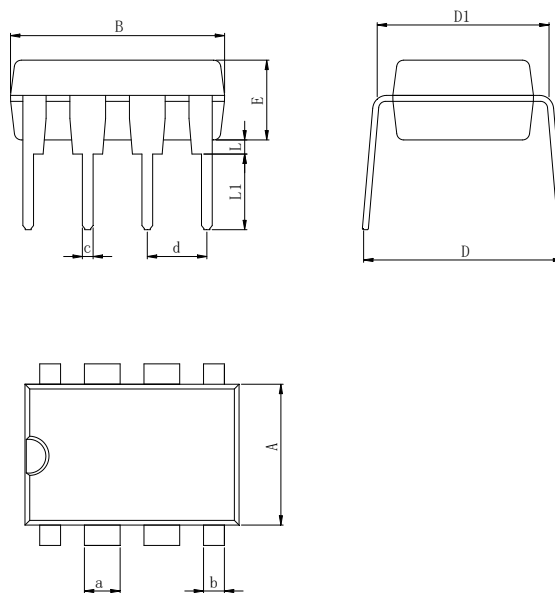C. Sixteenth SCLK falling edge

Physical Dimensions

SOP-8

Dimensions In Millimeters(SOP-8)								
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

DIP-8

Dimensions In Millimeters(DIP-8)										
Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	9.00	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	9.50	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

Physical Dimensions

MSOP-8
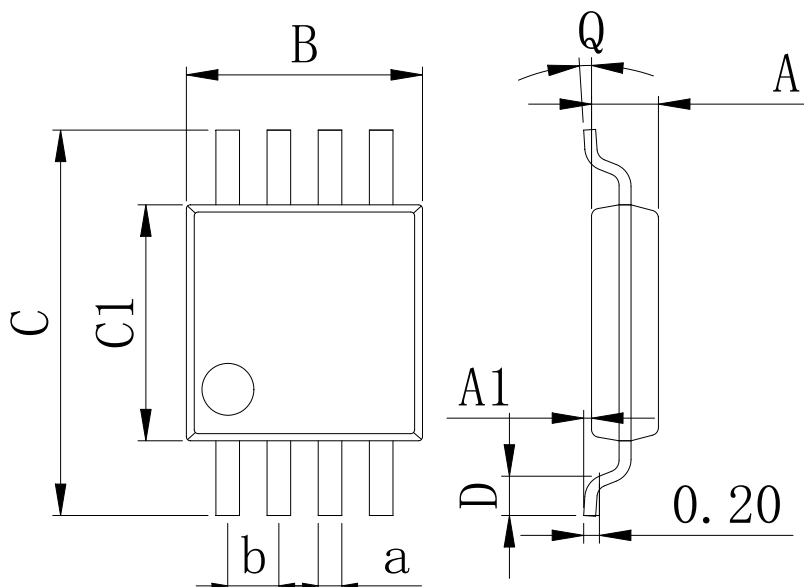
Dimensions In Millimeters(MSOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

Revision History

DATE	REVISION	PAGE
2015-8-9	New	1-12
2023-8-26	Update encapsulation type 、 Update Lead Temperature 、 Updated DIP-8 dimension	1、4、9

IMPORTANT STATEMENT:

Huaguan Semiconductor reserves the right to change its products and services without notice. Before ordering, the customer shall obtain the latest relevant information and verify whether the information is up to date and complete. Huaguan Semiconductor does not assume any responsibility or obligation for the altered documents.

Customers are responsible for complying with safety standards and taking safety measures when using Huaguan Semiconductor products for system design and machine manufacturing. You will bear all the following responsibilities: Select the appropriate Huaguan Semiconductor products for your application; Design, validate and test your application; Ensure that your application meets the appropriate standards and any other safety,security or other requirements. To avoid the occurrence of potential risks that may lead to personal injury or property loss.

Huaguan Semiconductor products have not been approved for applications in life support, military, aerospace and other fields, and Huaguan Semiconductor will not bear the consequences caused by the application of products in these fields. All problems, responsibilities and losses arising from the user's use beyond the applicable area of the product shall be borne by the user and have nothing to do with Huaguan Semiconductor, and the user shall not claim any compensation liability against Huaguan Semiconductor by the terms of this Agreement.

The technical and reliability data (including data sheets), design resources (including reference designs), application or other design suggestions, network tools, safety information and other resources provided for the performance of semiconductor products produced by Huaguan Semiconductor are not guaranteed to be free from defects and no warranty, express or implied, is made. The use of testing and other quality control technologies is limited to the quality assurance scope of Huaguan Semiconductor. Not all parameters of each device need to be tested.

The documentation of Huaguan Semiconductor authorizes you to use these resources only for developing the application of the product described in this document. You have no right to use any other Huaguan Semiconductor intellectual property rights or any third party intellectual property rights. It is strictly forbidden to make other copies or displays of these resources. You should fully compensate Huaguan Semiconductor and its agents for any claims, damages, costs, losses and debts caused by the use of these resources. Huaguan Semiconductor accepts no liability for any loss or damage caused by infringement.